IL7101

Ground Fault Interrupter Earth Leakage Current Detector

DESCRIPTION

The IL7101 is designed for use in earth leakage circuit interrupters for operation directly off the AC Line in breakers.

It contains pre regulator, main regulator, after regulator, differential amplifier, level comparator, latch circuit. The input in the differential amp latch circuit. The input in the differential amplifier is connecting to the secondary node of zero current transformer.

The level comparator generates high level when earth leakage current is greater than some level.

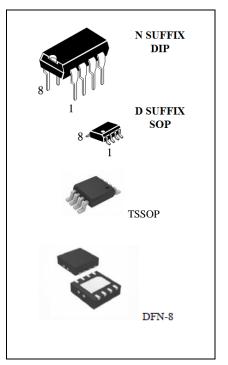
FEATURE

- Low Power Consumption (P_D=5mW) 100V/200V
- 100V/200V Common Built-in Voltage Regulator
- High Gain Differential Amplifier
- High Input Sensitivity
- Minimum External Parts
- Large Surge Margin
- Wide Operating Temperature Range (T_A= -30 to 85°C)
- High Noise Immunity
- Meet U. L. 943 standards

ORDERING INFORMATION

Device	Trip Voltage (rms)	Operating Temperature Range	Package	Shipping
IL7101SN	11.5mV to 13.86mV		DIP-8	Tube
IL7101AN	13.86mV to 15.6mV			Tube
IL7101SDT	11.5mV to 13.86mV		SOP-8	Tape& Reel
IL7101ADT	13.86mV to 15.6mV	T 20% to 85% C	30F-0	Taped Reel
IL7101STSDT	11.5mV to 13.86mV	$T_A = -30^\circ$ to 85° C for all packages		Terra & Deal
IL7102ATSDT	13.86mV to 15.6mV	ior an packages	TSSOP-8	Tape& Reel
IL7101SDNT	11.5mV to 13.86mV		DFN - 8	Tapol Rool
IL7102ADNT	13.86mV to 15.6mV		DEN-0	Tape& Reel





ABSOLUTE MAXIMUM RATINGS

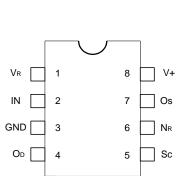
 Supply Voltage 	20V
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- Supply Current 8mA
- Power Dissipation 200mW
- Operating Temperature 30 to 85°C
- Storage Temperature 55 to 125°C

* Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.

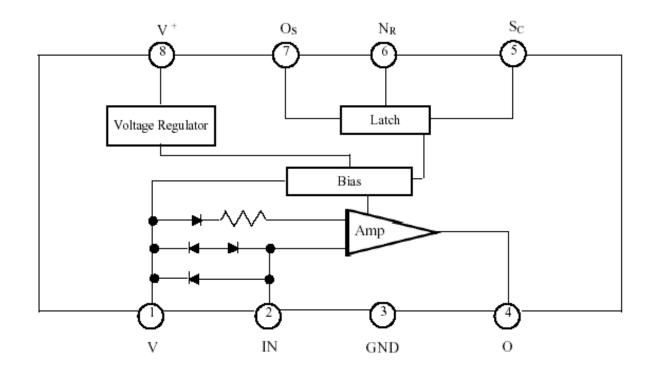
Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Pin Configuration



(Top View)

Block Diagram





Recommended Operating Condition: T _A =-30°C to 80°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX	UNIT
Supply Voltage	V*	12			V
Vs-GND Capacitor	Cvs	1			μF
O _S -GND Capacitor	Cos			1	μF

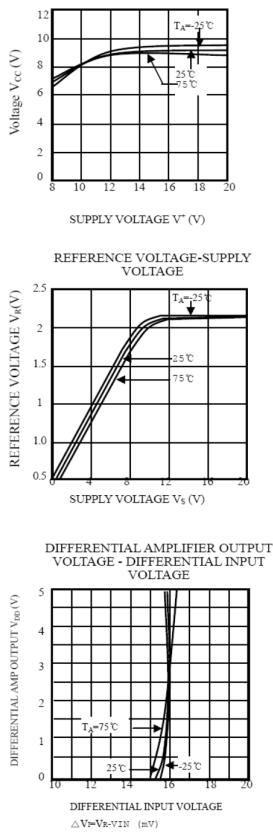
Electrical Characteristics

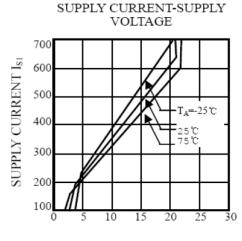
PARAMETER	SYMBOL	CONDTIONS		TEMP. (°C)	MIN.	TYP.	MAX.	UNIT	Test Circuit
		\/ ⁺ 40\/		-30	-	-	580		1
Supply Current 1	I _{S1}	$V^+=12V,$ V _R - V _I = 30 mV		25	-	400	530	μA	
				85	-	-	480		
Trip Voltage	V	$V^{+} = 16V,$		-30	11.5		13.86	mV	2
	V _T	$V_R - V_I = X$	IL7101A	85	13.86		15.6	(rms)	
Differential		$V^{+} = 16 V,$	•						3
Amplifier	I _{TD1}	$V_{R} - V_{I} = 30$	mV	25	-12	-	-30	μA	
Output Current 1		$V_{OD} = 1.2 V$							
Differential		$V^{+} = 16 V,$							4
Amplifier Output	I _{TD2}	$V_R - V_I = shc$	ort	25	17	-	37	μA	
current 2		$V_{OD} = 0.8 V$							
	I _o	V _{SC} = 1.4 V V _{OS} = 0.8 V	I _{SI} = 580μA	-30	-200	-			5
Output Current			I _{SI} = 530μA	25	-100	-		μA	
			I _{SI} = 480μA	85	-75	-			
S _C ON Voltage	V_{SC} ON	V ⁺ = 16 V		25	0.7	-	1.4	V	6
S _C Input Current	I _{SC} ON	$V^+ = I2V$		25	-	-	5	μA	7
Output "L" Current	I _{OSL}	V ⁺ = 12 V, V _{OSL} = 0.2 V	/	-30 85	200	-	-	μA	8
Input Clamp Voltage	V _{IC}	$V^{+} = 12 V,$ $I_{IC} = 20 mA$		-30 85	4.3	-	6.7	V	9
Differential Input Clamp Voltage	V_{IDC}	$I_{IDC} = 100 m/$	4	-30 85	0.4	-	2	V	10
Max. Current Voltage	V_{SM}	$I_{SM} = 7 \text{ mA}$		25	20	-	28	V	11
Supply Current 2	I _{S2}	$V_{OS} = 0.5 V,$ $V_{R} - V_{I} = X$		-30 85	-	-	1200	μA	12
Latch Circuit Off Supply Voltage	V+ OFF			25	0.5			V	13
Response Time	T _{ON}	$V^+ = 16 V,$ $V_R - V_I = 0.3$	V	25	1	-	4	ms	14



Typical Performance Curves

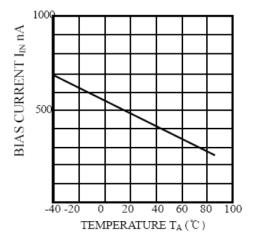




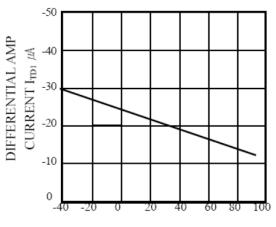


SUPPLY VOLTAGE $V^+(V)$

BIAS CURRENT-TEMPERATURE



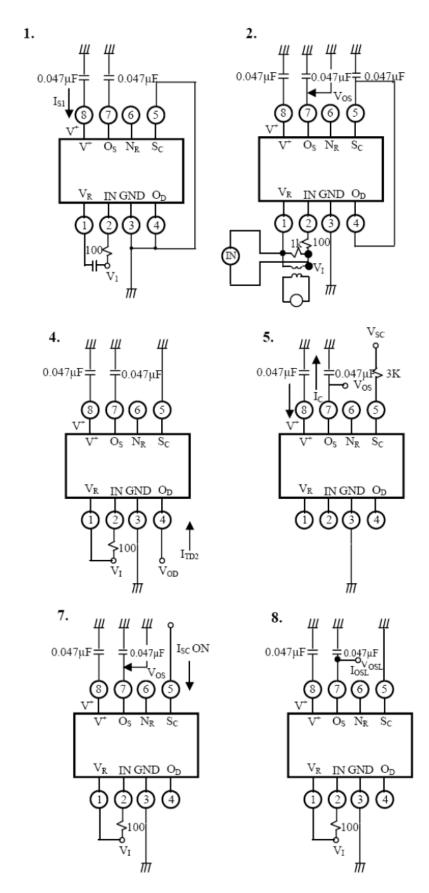
DIFFERENTIAL AMPLIFIER OUTPUT CURRENT-TEMP

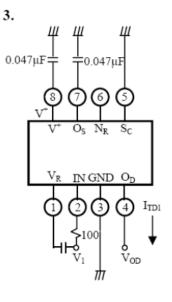


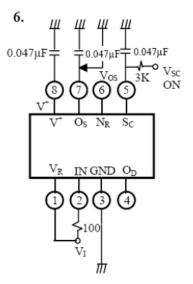
TEMPERATURE T_A (°C)

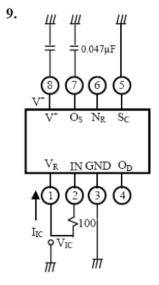


Test Circuit

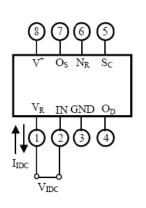


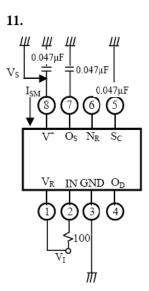


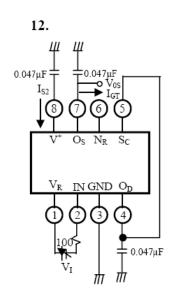




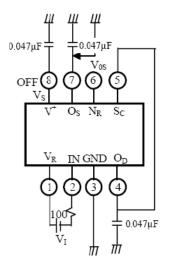




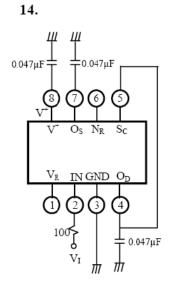




13.

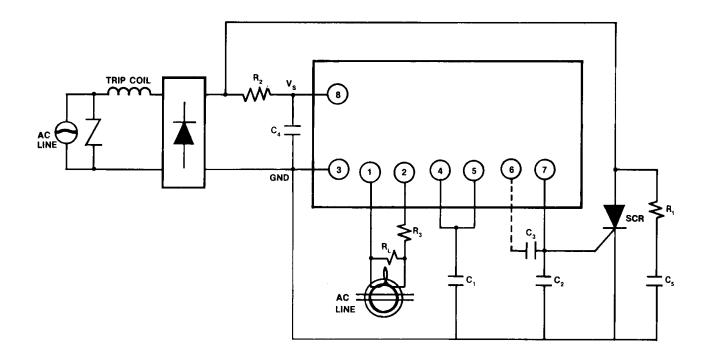


Ksemicon





Typical Application



Supply voltage circuit is connected as a previous diagram. Please decide constants R1, R2, C4, and C5 of a filter in order to keep at least 12V in Vs, when normal supply current flows.

In this case, please connect C4 (more than 1 μ F) and C2 (less than 1 μ F). ZCT and load resistance RL of ZCT are connected between input pin① and ②. In this case protective resistance (R3=100 Ω) must be insulted. Sensitivity current is regulated by RL, and output of amplifier shows in pin④. External capacitor C1 between pin④ and GND is used for noise removal.

When large current is grounded in the primary side (AC line) of ZCT, the wave form in the secondary side of ZCT is distorted and some signals doesn't appear in the output of amplifier. So please connect a varistor or a diode (2pcs.) to ZCT in parallel.

Latch circuit is used to inspect the output level of amplifier and to supply gate current on the external SCR. When input pin becomes more than 1.1V (Typ.) latch circuit operates and supply gate current in the gate of SCR connected to the output pin⑦.

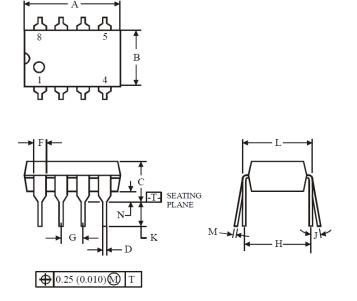
Pin⁶ can be used in the open state, but please connect capacitor (about 0.047 μ F) between pin⁶ and \bigcirc .

Capacitor C6 between pin (1) and GND is used to remove noise and is about 0.047 μF .



N SUFFIX DIP (MS - 001BA)



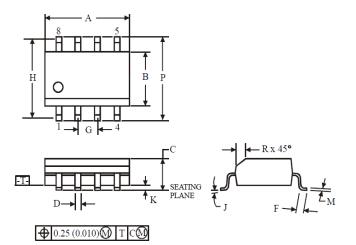


Dimension, mm MAX Symbol MIN 8.51 10.16 Α B 6.10 7.11 С 5.33 0.36 0.56 D 1.14 1.78 F 2.54 G 7.62 Η 0° J 10° K 2.92 3.81 L 7.62 8.26 Μ 0.20 0.36 Ν 0.38

NOTES:

 Dimensions "A", "B" do not include mold flash or protrusions. Maximum mold flash or protrusions 0.25 mm (0.010) per side.

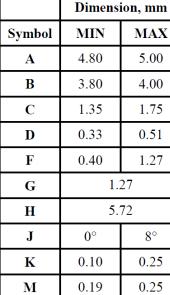
D SUFFIX SOP (MS - 012AA)



NOTES:

- 1. Dimensions A and B do not include mold flash or protrusion.
- Maximum mold flash or protrusion 0.15 mm (0.006) per side for A; for B - 0.25 mm (0.010) per side.





5.80

0.25

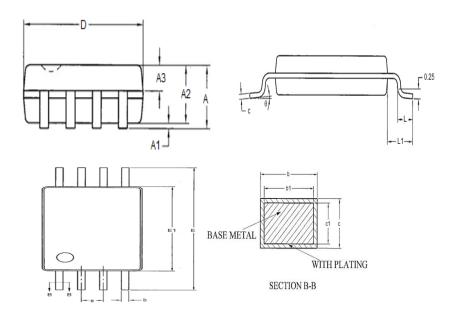
Р

R

6.20

0.50

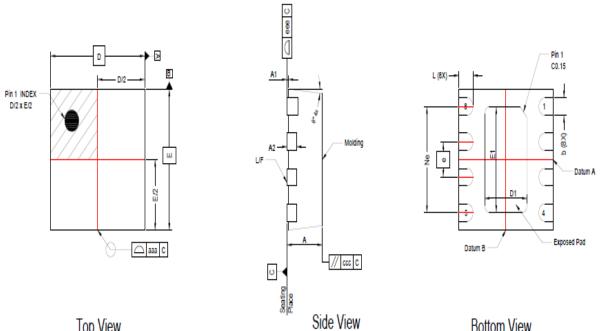
TSSOP-8 Package Dimension



SYMBOL	MILLIMETER				
SIMBOL	MIN NOM		MAX		
А	_	_	1.20		
A1	0.05	_	0.15		
A2	0.90	1.00	1.05		
A3	0.39	0.44	0.49		
b	0.20		0.28		
b1	0.19	0.22	0.25		
с	0.13	_	0.17		
c1	0.12	0.13	0.14		
D	2.90	3.00	3.10		
E1	4.30	4.40	4.50		
E	6.20	6:40	6.60		
e,	0.65BSC				
L	0.45 - 0.7		0.75		
L1	1.00REF				
θ	0	_	8°		



DFN-8 Package Dimension



Top View

B	60t	tor	n١	/iew

unit: 1	nm
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Items	DNF-8 Dimension				
	min	avg	max		
A	0.700	0.750	0.800		
A1		0.020			
b	0.200	0.200 0.250			
b1	No spec				
С	0.203BSC				
D	1.900	2.000	2.100		
D2	1.400 1.500		1.600		
е	0.5BSC				
Nd	1.400 1.500 1.600				
E	1.900	2.000	2.100		
E2	0.800	0.900	1.000		
L	0.250	0.300	0.350		

